Index

a
A-atoms tetrahedral sites 235
AB_2O_4 234
AB_2O_4 spinel 235
AB_2O_6 130, 150
AB_2O_6 barium strontium niobate $Ba_{5x}Sr_5$ 140
Ablation particles 54
ABO_3 (barium titanate) 18, 82, 126, 140, 149, 225, 235
ABO_3 Pb 103
Abrahams, S.C. 151
Abrikosov, Alexi A. 18
Absorption of high energy electron beam heats 63
Acceptors Group III elements 158
  acidic-alkaline 220
AC/DC 185
Acoustical amplifiers and acousto-optical devices 221
Acousto-optic materials 254
  active ferroelectric STN 139
AC power source 194
AC power supply 136
AC signal 108, 112–16
AC source 135, 187
AC supply 112, 185
actuators, micromachined PZT 117
AC voltage 108, 112
AFC (alkaline fuel cell) 224
AFE 141
AFE phase 141
AFM (atomic force microscope) 57, 68–71, 106, 108, 112, 117
  image 69
  imaging 69
  probe 69
AFQjCNHekD116tBBdx8ycrQ1z-Eo6LVkk1Q&ust 47
Ag 2, 5, 9, 27, 154, 176–78, 196, 216, 230
Ag/Al 176
AgI_2 224
Ag/Si contact 178
Ainger 151
airflow 221
Akasaki, Isamu 181
Akbar, S.A. 213
Alabama xiii–xiv, 46, 120
  Albert Einstein 1, 8, 33, 57, 240
AlGaInP/GaAs 181
AlGaN 182, 212
AlN 113, 154
Al_2O_3, xiii 41, 53, 75, 154, 183
Al_2O_3 Trigonal 250
$AlPO_4$ 53
Al/Si 178–79
Al/Si contact 178–79
Aluminum 2, 5, 9, 17, 158, 166, 218, 231–32
  gallium nitride UV 182
  oxide Al_2O_3 231
  X-rays 67
Amano, Hiroshi 181
American Ceramic Society xiv, 1, 33, 35, 57, 73, 95, 121, 153, 173, 247, 257, 259, 261, 263
American mathematician 149
American Physical Chemist 8
American physicist Peter 103
American Physicists 12, 19
Amperé's law 14
Amsterdam 150
  ancient 229
Anderson, Phillip 23
Anisotropy 76, 93, 120, 129
Anomalous PV 222
  anomalous 169–70, 222
Antennas 240
Antiferroelectric energy storage 225
  antiferroelectric 102, 141–42
Anti-ferromagnetic Cr_2O_3 103
  antimony sulfo-iodide 140
Antiferromagnetic and ferroelectric effects 103
Antimony-sulfo-iodide 148
Antiparallel configuration of domains 237
Appendix 257, 259, 261, 263
Appendix II 164
Applications of ferroelectricity 151
Applications of multiferroics 95, 105
Applications of PTC and NTC thermistors 209
Applications of Pyroelectricity 146
Applied Chemistry 42
Applied Superconductivity 31
Ar 16–17, 35, 48, 52, 75, 230, 240
Ar Krypton 16
Arrhenius equation 210
Arsenic 158
Ar SiO 52
Ashcroft, N.W. 31
assistants Walter Friedrich 61
associated issues 95, 103
  asymptotic 134
Atalia, M.M. 213
ATO acts 183
ATO layer by RF magnetron sputtering 183
Atomic and nuclear physics 25
Atomic Force Microscope *see* AFM (atomic force microscope)
Atomic plane 60–61
atoms, body diagonal Ti^{4+} 127
ATO SnO_2 183
A-type cations 130
Au/Al 176
Aufbau 238
Aufbau principle 238
Auger electrons 64
Auger surface analyzer 63
Augustin, Charles 73

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Augustin-Jean Fresnel 249
Au/Si contact 178
Austenite 38
Austria 12, 14
Austrian Physicist Christian Doppler 118
Average frequency 180
Average photon energy 180
Avogadro's number 27, 86, 236, 259
Axial and angular-based definitions of crystal classes 79
Azad, A.M. 213
Azaroff, L.V. 15, 31

b

Ba (barium) 18, 127–28, 231, 235, 237–38
Ba Radium 16
$Ba_{1-x}Sr_x$ 147
Ba_2 127
Ba^{2+} ions occupy 127
$Ba_2Sr_3Nb10O_{30}$ 130–31
Ba_4 130
Ba-based fluorides 103
$BaCoF_4$ 123
BAeff 237–38
$BaFeF_4$ 103, 123
$BaFe_{12}O_{19}$ 233
Ba-ferrite 233
Ba-ferrite Hard Ceramic 239
Balmer series 10
$BaMnF_4$ 103
$BaNbO_3$ 130
Banerjee, S. 171
$BaNiF_4$ 103, 123
Bardeen, John 18, 19, 23, 29, 190
Barium oxide (BaO) 50, 231
Barium strontium titanate $Ba_xSr_{1-x}TiO_3$ 140
Barium titanate ($BaTiO_3$) 52, 66, 107, 111, 123, 125–26, 128–29, 131, 137–38, 141–42, 148–49, 207–8, 218, 221, 223, 251
Barium titanate domains 138
Barquinha, P. 213
Barrier height (Φ_0) 188
Barrier height, lowest Schottky 179
Barthélémy 120, 242, 245
based 194, 204
Bartholm, Rasmus 249
Basic concepts 33
Basic crystallographic properties of cubic crystals 85
Basic crystal structures 73, 77
Basic experimental configuration of scanning force microscopes 68
Basic formula 232
Basic formulations 103
Ba-Sr-niobate series 130
$BaTiO_3$ 36, 51, 66, 75, 82, 89, 107, 114, 123, 126–28, 140–41, 149, 207, 221, 223
$BaTiO_3$ $LiNbO_3$ $LiTaO_3$ Pb_{1-x} 111
$BaTiO_3$ unit cell 127
batteries and fuel cells 224
Battery-supercapacitor 220
Battery-supercapacitor hybrid (BSH) 220
Battery systems for electrically powered vehicles 228
$Ba_xSr_{5-x}Nb_{10}O_{30}$ 130
BCSCO 18
BCS theory 19, 23
BCS theory of superconductivity 18
Becquerel, A.E. 222
Bednorz, Georg 18
Bell Laboratories 44, 47, 51, 190, 198
Bell Telephone Laboratories 213
Beratan, H.R. 55
Berkeley 103
Bernstein, J.L. 151
Beryllium 16
Betzig, Eric 59
B-fields 248
BFO 61–62, 104
BFO film 67, 70
BFO for bismuth ferrite 104
Bhalla, A.S. 151
Bi 15, 67, 99
Biard, R. 160, 171, 181, 213
Biaxial crystals 249
Bi-based perovskite 227
Bibes, M 120, 242, 245
$Bi_2CaSr_2Cu_2O_8$ 18
$Bi_2Ca_2Sr_2Cu_3O_{10}$ 18
Bi_4f of Bismuth ferrite film 67
$BiFeO_3$ 103–4, 223
$BiFeO_3$ Bismuth 242
$BiFeO_3$/CoFeB bilayer 242
$BiFeO_3$ Perovskite 141
$Bi_4Ge_3O_{12}$ 54
$BiMnO_3$ 103
Binary phase diagrams 35
Binding energy of electrons 67
Binding forces in solids 73
Binding forces in solids and essential elements of crystallography 73, 75, 77, 79, 81, 83, 85, 87, 89, 91, 93
Binning Gerd 68
Bi_2O_3 186
Biodiesel 216
Biopower generation Hydropower Wind 216
Biosensors 241
bipolar junction transistor *see* BJT (bipolar junction transistor)
Birefringence crystals 254
Birefringence Δn 249
Bismuth silicate $Bi_{12}SiO_{20}$ 251
$Bi_4Ti_3O_{12}$ 140
BJT (bipolar junction transistor) 51, 190, 193, 195–96, 212
BJT, classical solid-state 193
BJT devices 193, 196
BJT transistor 195–96
Bloch, Felix 28
BNdFeO 227
BNT 141
Bohr, Niels 10–11
Bohr designations 14–15
Bohr magnetron 24, 236, 238, 242, 259
Bohr's model of hydrogen atom 10–11
Bohr's Theory 7, 11
Bohr's Theory of Hydrogen Atom 10
Boltzmann, Ludwig 24
Boltzmann constant 6, 25, 155, 164, 178, 259
Boltzmann statistics 24, 155
Bonded H_2 74
Borchardt-Ott, W. 79, 93
Born, Max 12
Boron 17, 158
Bose-Einstein distribution function 25
Bottom electrode 114, 117, 138, 222–23, 252
Bragg angle 253, 255
Bragg condition 62, 71
Bragg diffraction 71, 253
Bragg diffraction angle 71
Braggs William and Lawrence 60
Bragg's equation 253
Bragg's law 60–62
Bragg's law of XRD 61
Brattain, Walter 190
Braun, Wernher von 173
Bravais, Auguste 78

Bravais lattice Order of symmetry 79
Bravais lattices 78–79, 86–89, 91–92
Brenner, S. E. 55
Brewster 143
Brian, D 18
Brian David Josephson 22, 29
Brian 22
Bridgman 34, 54
brilliant 29
Brillouin, Léon Nicolas 28–29, 253
Brillouin zones 28–29, 81
British mineralogist 80
British physicist 188
Broglie, Louis de 11–12, 22, 29, 63
Broglie Hypothesis 11, 63
Broglie of France 11, 29
Broglie principle 7
Broglie relationship 12, 59, 160
Broglie wavelength 30
Brookhaven National Labs 191
Brophy, J.J. 15, 31
BSH (Battery-Supercapacitor Hybrid) 220
BST 140, 147
BT *see* barium titanate ($BaTiO_3$)
BT $BaTiO_3$ 131
BT crystal lattice 66
BT layer 66
BTO 104
BTO capacitors 140
BTO/CFO 104
BTO electro-optics 140
BTO/LMO 104
BT thermistor 207
B-type cations occupy 130
Buchanan, R.C. 213
Bulk $BiFeO_3$ 103
Bulk PV effect 222
Bulk PZT actuator 112
Byer, R.L. 145, 151

C

Ca atoms 82
$CaCO_3$ 55
$CaCu_3Ti_4O_{12}$ 55, 180, 196, 220
Ca-Cu-titanate 220
Cadmium 17
Cadmium telluride CdTe 251
CaF_2 41, 54
Ca_2FeReO_6 242
Ca^{2+} ions occupy 127
Ca Strontium 16
Calcine ball 39
Calcite $CaCO_3$ Trigonal 250
CaO 41
Capacitance C_1 187
Capacitance measurement 136
Carbon dioxide CO_2 35
Carr, W. N. 213
Carver Company 40
Ca-Sr-Co-oxide ($Ca_{0.4}Sr_{0.6}CoO_3$) 209
$CaTiO_3$ 82, 92, 127, 149
$CaTiO_3$ crystal 249
$CaTiO_3$ lattice constant 92
$CaTiO_3$ structure 127
$CaTiO_3$ unit cell 127
Ca-Zr-In-oxide 209
CB *see* Conduction band (CB)
CCTO 66, 180, 196–98, 220
CCTO capacitor 198, 220
CCTO gate 196
CCTO gate oxide 197
CCTO supercapacitor 225
CCTO supercapacitor material 220
CCVS (constant current voltage supply) 194, 198, 212
CCVS and transconductance amplifiers 194
Cd 17, 86, 216, 234
CdA 137
Cd/A 137
Cd_2FeNbO_6 123
$CdFe_2O_4$ 235
Cd-ferrite 235
CdO 179
CdS 17, 84, 116, 154, 167
CdSe 17
CdTe 17, 90
CeF_2 54
Centrosymmetric, symmetry symbol Pyroelectric Piezoelectric 91
Centrosymmetric and Noncentrosymmetric Crystals 87
Ceramics and single crystals of piezoelectric materials 114
Cesium 141
Ceylon 143
Ceylon magnet 143
CFO 104
CGS 232
CGS system 231
CGS system of units 243
CH_4 74
Chang, Kai 150, 255
Change in resistance 204
Characteristic symmetry 250
Chemical formula SiO_2 111
Chemical pollutants 215
Chen, L.H. 245
Cheong, S.-W. 120
China 203, 222, 229
Chromium 17
CiG 187
Cl 82
Cl- ions 82
CIP (Cold Isostatic Pressing) 41
CIP methods 41
Classical applications 240
classical Newtonian 160
of Ferrites 229, 239
Cl-ions 74
Clive Randall 42
CMOS processing 112
CMR 104, 239, 241
CMR effect and perovskite structure 241
CMR effects 239, 241–42
CMR materials 240–41
Cn 85
Co 6, 16, 28, 52, 86, 101, 107, 209, 230–31, 234, 239–40, 244
CO_2 40, 46, 209
Co Cr Cu Fe 216
Co Cr Cu Fe Mg 216
Coercive point Hc 232
$CoFe_2O_4$ 104, 233, 235
$Co_{0.8}Fe_{2.2}O_4$ 107
Co-ferrite 233, 235
Co-ferrite hard magnetic recording 239
CO_2 gas 41
Cold Isostatic Pressing *see* CIP (Cold Isostatic Pressing)
Columbian interaction 68
Common examples of electrolytes 224
Comparative representation of insulators 3
Comparison of refraction index and permittivity 7
Compiled 156, 167
Components V1 136
Composite Table 90
Composition $A_{0.2}B_{0.8}$ 55
Composition $A_{0.5}B_{0.5}$ 37
Composition L_1 36
Composition S_1 36
Compositions $A_{1-x}B_x$ 35

Computer-controlled growth process 52
Concentration molecular 54
Conditions for ohmic and nonohmic 178
Conduction band (CB) 2–3, 25, 29, 154–60, 162, 170–71, 175, 188
Configuration for circuit protection 185
Configuration for measurement of sample resistance 163
Configuration of micromachined device for energy harvesting 222
Co nickel 17
Constant current voltage supply *see* CCVS (constant current voltage supply)
Constitutive equations for piezoelectricity 110
Contact potential 178, 212
Controlled melting 54
  conventional MOSFET 196
  conventional semiconductor 199
Conventional-Microscope 71
Converse PE-effect 114
CoO 179
CoO_2 186
Cooper, Leon N. 18, 19, 23, 29
Cooper pairs 19, 23, 29
Cooper pairs breaks 23
Cooper pairs wander 23
Cooper pair tunneling 23
Corak, W.S. 213
Correspondence of spectral series 14
Costello, Lacy 214
Co-TiO_2 242
Coulomb 24, 73, 263
Coulombian force 73
Coulomb interactions 24
Coulomb's constant 73
Coulomb's law 73
Coupled dielectric phenomena xiv
Coupled nonlinear effects in electroceramics 121, 123, 125, 127, 129, 131, 133, 135, 137, 139, 141, 143, 145, 147, 149
Coupled pyroelectric 122
Courtesy of electroceramics Lab 40
Courtesy of Electronic Materials Laboratory 41, 46
Courtesy of Encyclopedia Britannica 65
Courtesy of Texas Instruments 51
Cr 5, 16, 86, 177, 230, 234, 244
CRC Press 55
Cr Manganese 17
Cr_2O_3 103–4, 186
CrO_2 Chromium 242
CRT 209
Crucible shaft 52
Crucible susceptor 52
Crystallize, ferroelectric $BaTiO_3$ 83
Crystallographers, brilliant French 78
Crystallographic considerations for piezoelectricity 108
Crystal structure above TC Below TC 131
Crystal structure dependence of polar axis in barium titanate 129
Crystal system 91
Cs 75, 131
$CsCrwS_4$ 103
CSD-prepared PZT films 120
Cs Francium 16
$CsPbCl_3$ 141
Cu 2, 5, 9, 17–18, 27, 59, 66–67, 86, 154, 178, 230–31, 234, 244
Cu/Al 176
Cu Auger 67
Cu_2O 155, 179
Cu_2O_3 186
Cubic Close-packed Structures 73, 85
Cubic $SrTiO_3$ 40
Cubic Triclinic Tetragonal Hexagonal Monoclinic Orthorhombic Trigonal 109
CuO 18, 55, 102
Cuprous oxide 179
Curie 20, 125–26, 132–34, 139, 142, 234, 244
Curie brothers 220
Curie constant 126, 134, 234, 244
Curie point 34, 102, 123–29, 133–35, 139–42, 148–49, 207, 231, 234, 236–37, 242–43
Curie temperature 20, 125–26, 131–32, 134, 149, 234, 242–43
Curie temperature and transition point 148
Curie temperature of ferro-magnetic materials 238
Cu/Si contact 178
$CuSO_{4.5}$ H_2O 54
Cz-growth 52
Cz-growth chamber 52
Cz-growth experiment 51
Cz-growth method 52
Cz-growth systems 52
Cz-method 51–52
Czochralski, Jan 34, 51
Czochralski crystal growth method 49
Czochralski crystal growth technique 51
Czochralski growth 54, 63
Czochralski growth method 51
Czochralski method 51
Cz-technique 51–52

d

Dallas 51, 213
Dalton's law of partial pressure 211
Danish physicist 10
DARPA 220
Datta, S. 213, 241, 245
Davisson, Clinton 12
DC (direct current) 23–24, 108, 113, 177, 185
DC offset 145
DC power source 194
DC/RF power supply 48
Debye, Peter J. 103, 253
Debye temperature 5
Defense Advanced Research Project Agency (DARPA) 220
Defining parameters 77, 215, 217
Defining properties of solids 1
Dekker, Merkel 213
Delin, K.A. 18, 31
Demjanovic, D. 151
Denmark 249
Density of states and fermi energy 161
Determination of bandgap 164
Determination of contact potential and depletion width 178
Determination of direct and indirect bandgap 166
Determination of mobility 166
Determination of radiation hardness of IHC 190
Determination of resistivity 162
Deuterated TGS 147
Deutsches Museum 65
Devonshire 130
Devonshire Mean Field Theory of Ferroelectricity 121, 130

Dielectric Phenomena in Solids 120, 150, 228
Digital displacement transducers electrocaloric 122
Dimensionless 232
Dirac, Paul 24
Direct and indirect bandgap 159, 166
Direct band-to-band transition 159
Direct current *see* DC (direct current)
Direct infrared 167
direct PE-effect 114
Direct Potentially 167
dispersive 57, 71
Dissertation 71, 120
DOE 237
Domain configuration 137, 237
Domain wall 126, 138, 236–37
Dominant forces 95
Dominant forces and effects in electroceramics 95, 97, 99, 101, 103, 105, 107, 109, 111, 113, 115, 117, 119
Dong, L. 214
Donors Group 158
Doped BT 207
Doped lead-zirconate-titanate 227
Doped LSTO 242
Doped Mn_3O_4 207
Doped p-GaAs 181
doped 186
Doping Group IV semiconductors 17
Doppler effect 115, 118
Doppler shift 118
double-layered low-voltage 186
Double-sided PZT films 120
Dransfeld, K. 69, 71
Ducharme, S. 151
Dutch merchants 143
Dynasty, Han 229

e

ECSA 71
EDAX 57, 65–66
EDAX energy 34, 71
Edward, J.S. 145, 151
Edwin Powell Hubble 229
Edwin 168
E-FET 191, 196–97, 212
E-FET device 196, 198
E-FET transistor 197–99
Effect and associated issues 95, 103
Effect of Nb doping on pyroelectric property 151
Effusion cell 47–48
E-field 197
E-field oscillation 248
EFM 175
EFS 176
Egashira, M. 214
Einstein, Albert 8, 11
Einstein's equation of electron emissivity 8
Einstein's matter 11
Einstein's photoelectric effect 7
Electrical conductance 1
Electrical conduction in semiconductors 153
Electrically Powered Vehicles 228
Electrical properties 31, 171, 214, 245, 255, 261, 263
Electric field dependence of polarization of pyroelectric material 144
Electric field EC 176
Electric field EEC 167
Electric field tuned varistor 196
Electric flux density 263
Electric polarization reversal and memory 120
Electroceramic magnetics 229, 231, 233, 235, 237, 239, 241, 243, 245
Electroceramics xiii–xiv, 1–2, 6–8, 16, 18–20, 33–55, 57–58, 73–74, 95–151, 153–54, 173–74, 192–94, 214–18, 228–30, 247–48
Electroceramics and green energy 215–227
Electroceramic semiconductor devices 173–213
electroceramic 199
Electroceramics Lab 40
Electromechanical 221
Electron and hole motilities 168
Electron-camera 47
Electron devices 245
Electron devices Soc 213
Electronic analog 213, 245
Electronic materials and devices 31, 245, 255
Electronic Materials Laboratory 21, 40, 41, 46
Electronic processes in materials 31
Electro-optic deflectors 252
Electro-optic modulators 213, 245, 252
Electrothermal effects 96, 98, 144
Element Li, third 16
Elements Atomic number 158
Elements Carbon 17
Elements of group VIII 16
Element titanium 17
Embedded H-FET transistors 201–2
Embedded magnetic field effect transistor 198
Embedded voltage biased transistor 190
embedded 194, 196, 198, 200
Emitted radiance 182
Emitting diodes lasers 154
Emitting UV 44
emitting 181
Encyclopedia 150, 255
Encyclopedia Britannica 65, 71
Energies of X-rays 59
Energy bands in semiconductors 153, 155
Energy Enx 161
Energy-hungry countries 222
Energy industry 228
Engineering materials 171
Enrico 24
Equilibrium phase diagram 33
Eremetes, Mikhail 19
Ergebnisse 120
$ErMnO_3$ 103
Ernest 10
Ernst 63
Erwin 12
Esaki, Leo 18, 22
ESCA 57, 66–67
ESCA (Electron spectroscopy for chemical analysis) 71
Essential elements xiv, 26, 28, 153
Essential elements of quantum mechanics 1, 7
Essential theoretical concepts 229, 235
Europe 143
Europeans 143
Evans Library xiv
Ewald, Paul Peter 81
Paul 24
Ewen, R. J. 214
Examples of donors and acceptors 158
Examples of transparent binary metal-oxide semiconductor group 179
Excimer lasers emit UV radiation 44
Expanded piezoelectric zone 97
Expanded pyroelectric zone 98

Experimental determination 104, 121, 134, 137, 153, 162
Experimental determination of piezoelectric coefficients 95, 111
Experimental determination of pyroelectric coefficient 145
Experimental setup for measurement of pyroelectric 146
Experimental setup for monitoring photovoltaic effect 223
Extrinsic n-type 174
Extrinsic p-type 174

f

Farad 263
Faraday, Michael 207
Faraday's law 19, 239
Fatuzo, E. 125, 150
F-D-distribution function 24
F-D-statistics 24
Fe 5, 9, 16, 86, 101, 106–7, 141, 191, 216, 223, 230–31, 234, 237, 239–40, 243–44
Fe amounts 239
Fe Cobalt 17
Fe/Cr superlattices 241
Fe Mn Pb 216
$Fe_{0.5}Nb_{0.5}$ 103
$Fe_{0.5}Ta$ 103
FE to ferroelectric and PE 141
Fe^{2+} 242
Fe_2O_3 191, 229–30, 234–35
Fe_3O_4 53, 101, 107, 203, 207, 229–30, 234–35, 243
Fe_3O_4 magnetite 242
Fe_2TiO_5 46, 51, 180, 191
Fe_2TiO_{12} 180
Fe^{3+} ions 242
FE-AFM 106
FE-AFM layer 106
FE-FM Heterostructures Electro-optical device 122
FeO 102, 179, 229, 235, 237
Fe-PV 222
Fe-PV devices 224
Fe-PV effect 222–23
Fe-PV materials, new 224
Fe-PV solar cells and piezoelectric power generator 225
FeRAM 105, 139, 149–50
FeRAM devices 141
FeRAM structure, based 138
FeRAM technology 141
Fermi, Enrico 1–2, 24, 26, 30, 155
Fermi-Dirac distribution plot 26
Fermi-Dirac distribution 155
Fermi-Dirac distribution function 1–2, 24
Fermi-Dirac statistics 30, 154–55
Fermi-Dirac statistics merges 155
Fermi energy 3, 25–27, 29–30, 155–56, 161–62, 167, 170–71
Fermi function 25–26, 155
Fermi level 3, 25, 29, 155–56, 164, 170–71, 174–75, 188
Fermi level changes 29
Fermi levels merge 175
Fermi momentum 26
Fermi temperature T_F 26–27
Fermi velocity 21, 26–27
Ferroelectric 120
Ferroelectric and ferromagnetic coupled memory 105
Ferroelectric and ferromagnetic effect 103
Ferroelectric Crystals 89, 124, 126, 136, 151
ferroelectric Curie point 103, 145
ferroelectric Curie temperature 207
Ferroelectric parameters 121, 125, 134
Ferroelectric photovoltaic devices 222, 228
Ferroelectric/Piezoelectric layer 104
ferroelectric-piezoelectric 116
Ferroelectric PZT 139
Ferroelectric RAM 139
Ferroelectric Random Access Memory 149
Ferromagnetic coupled memory 105
Ferromagnetic layer 106
Fert, Albert 240
FeS 123
FET *see* field effect transistor (FET)
$FeTiO_3$ 123, 191
$Fe_{0.67}W$ 103
Feynman model 27
Feynman, Richard 12
Fiebig, M. 99–100, 104, 120
Field effect transistor (FET) 183, 191, 196–99, 211–12
Films, oriented YIG 236
First electromagnetic coil 64
First heat treatment 39
First Landau's theory of second-order phase transition 130
First magnetoelectric 103
first order phase transition (FOPT) 128–29
Flux growth method 50
Food Processing 209
FOPT *see* first order phase transition (FOPT)
Forbidden band 27–29, 155
Forbidden band II 28
Force microscopy 68
Fortunato, E. 181, 213
forward biased 177
Foundations of Applied Superconductivity 31
Fourfold 88
Fourier transform 81
Four-Point Probe 163
FRAM 138
France 11, 29, 60, 123, 237, 240, 249
Frederick, J. 151
French mineralogist 88
French physicist 28, 73, 102–3, 141, 222, 234
French physicist Brillouin 253
French physicist brothers 108
French Physicist Pierre Curie 148
Frequency dependence of energy density of CCTO 220
Frequency dependence of IHC 194–95, 198–99
Frequency dependence of optical absorption coefficient 167
Frequency dependence of permeability and loss tangent 233
Frequency dependence of power 222
Frequency spectrum of permittivity 6
Frequently used symbols and units 259, 263
Fridkin, V. 151
Friedrich Carl Alvin Pockels 249
FTJ (ferroelectric tunnel junction) 122, 139
Fukumura, T. 213
Fundamental nature of electrical conductivity 1, 4
Fundamental optical properties 248
Fundamental physical constants and frequently used symbols and units 259
Fused quartz 154, 248
Fused quartz SiO_2 254
FWHM 61–62

g

GaAs *see* Gallium arsenide (GaAs)
Gadolinium molybdate $Gd_2(MoO)_3$ 140
Ga Ge 216
Ga Indium 17
Galileo Galilei 58
Gallagher, R.C. 213
Gallium 17, 158
Gallium arsenide (GaAs) 2–3, 30, 47, 62, 66, 82, 84, 154, 156, 160, 167, 176–77, 181–82, 251, 254
GaN 84, 154, 181–82
GaN III 168
Ga_2O_3 173
GaP 84, 182
Gauss 19, 203, 211, 232, 243
Gaussian 231–32
Gaussian units 231
Gauss magnetic fields 243
Gaussmeter 205
GB (grain boundary) 40, 126, 186–88, 196, 204, 207, 211, 213
GBG junction 190
Gd 18, 230, 235
Gd-Ga-garnet 49, 52
Gd-Sc-Al garnet 52
Gd-Sc-Ga garnet 52
Ge 2–4, 7, 30, 51, 54, 84, 92, 154, 156, 158, 161, 166, 171, 177
Ge IV 168
Ge Tin 17
Geiger, P.H. 213
Gem quality crystals 54
General Capacitor 218
general 34
Generated lattice type 89
generating 59
Generation of Sound 114
Geothermal electricity 216
Gerber 68
Gerd Binning 64
Gerlach, Walther 14
German crystallographer 88
Germanium (Ge) 231
German physicists 14, 81, 249
German Proverb 33
German speaking countries 208
German word 78, 238
Germany 2, 7–8, 12–13, 19–20, 27, 59–61, 63, 65, 69, 96, 120, 164, 176, 238, 240
Germer, Lester 12
Gerog Ohm 2
GHz 6, 115
Giaever, Ivar 18, 22
Giaever junction 23
Giaever tunneling 22
Giant magnetoresistive 203
Giant PV 222
Gibbs, J. Willard 34, 130–32, 134, 148–49
Gibbs energy 149
Gibbs function 131, 148
Gibbs phase rule 34–35, 37, 55
Ginsberg 121, 130
Ginsburg 130
Ginsburg's work 130
Ginzburg, V. 18
Gittertheorie 120
Glossary 29, 54, 70, 91, 118, 148, 170, 210, 227, 242, 254
G_m 193–94, 197–98
GMO Electro-optics 140
GMR 239, 243
GMR and CMR effects 239, 241
GMR and CMR materials 240
GMR effect 240–41, 243
GMR superlattice device 241
Goddard, D.W. 55
Goeking, K.W. 53, 55
Gong, G. 245
GPS 115
GPS system 229
Grain boundary *see* GB (grain boundary)
Grain resistance RG 186
Great Britain 22
Greek origin 58
Greek philosopher 143
Greek philosophers Thales 203
Greeks 54, 58, 118, 143, 203
Geiger, Greg xiv
Greek word 43, 143
Greek word piezo 108
Grondahl, L.O. 213
Group II 78, 108–9, 156, 190, 235
Group II members 78
Group II point groups 108
Group III 16–17, 78, 156–57, 190
Group III members 78
Group IV 17, 74, 83–84, 156–57, 190
Group IV atoms 157
Group IV elements 157
Group IV semiconductors 157
Group VI elements 17
Group VIII 16
grown ferroelectric 145
Grünberg, P. 240
GSAG 52
GSGG 52
Günther, K.G. 46, 55
Güthner, P. 69, 71

h

Hall, Edwin 168
Hall conductance 169
Hall conductivity 170
Hall constant 169
Hall effect 168–69, 200, 205
Hall effect experiment 169, 171
Hall effect Gaussmeter 203
Hall effect measurements 169
Hall effect method 166, 168
Hall effect sensor 203
Hall effect set 200
Hall element 213
Hall force 168–69
Hall probes 169
Hall voltage 169, 200
Hamilton, Sir William 12
Hamiltonian, $\hat{H}$. 13
Hamiltonian, corresponding 12
Hamiltonian mechanics 12
Hamiltonian operator 12–13
Han, Hui xiv
Handbook 42, 55
Harold, Stern xiv
H-atom 236
Hawking, Stephen 153
HAXRD (high-angle X-ray diffraction) 61
Haynes 166–68
Heatable sample stage 45
Heated cathode 64
Heated Knudsen sources 46
Heating effects in Thermistors 207
Heat Vibration 216
Heckmann, G. 96, 120
Heckmann diagram 95–96, 99
Heckmann diagram in figure 96
Heisenberg model 235
Heisenberg's Uncertainty Principle 7, 11, 13
Heisenberg, Werner 13
Helium 16
Hell, Stefan W. 59
Henry H 263
Herbert, J.M. 147, 151, 214
Hermann, Carl 88
Hertz, Heinrich 8, 263

Hexagonal and Cubic Close-packed Structures 73, 85
Hexagonal and trigonal structures 81
Hexagonal Uniaxial 250
H-FET 196, 198, 212
H-FET and E-FET transistors 198
H-FET device 199
H-FET transistor 199, 201–2
H-field 211
Hg 17, 59
$HgBa_2Ca_2Cu_3O_8$ 18
High-angle X-ray diffraction (HAXRD) 61
  high-angle 61
High densification and compaction 41
High density MRAM 241
High-intensity ultrasound 115
High-resolution XPS spectrum of Bi4f of Bismuth ferrite film 67
High temperature and high pressure growth 53
High Temperature Solution Growth *see* HTSG (High Temperature Solution Growth)
High temperature superconductor oxides and colossal magnetoresistive materials 149
High voltage source 64
H-ions 75
HIP (Hot Isostatic Pressing) method 41
HIP and CIP methods 41
Historical perspective 121, 123, 143
Ho 235
Hoffmann, B. 204, 214
Holograms 254
Hooke's law 68, 97, 110
Hooten 137–38, 151
Hot Isostatic Pressing *see* HIP (Hot Isostatic Pressing) method
HTSG (High Temperature Solution Growth) 50–51, 54
HTSG growth 54
HTSG method 51–52
Hua, Z. 214
Human ears 255
Hund, Friedrich 238
Hund's rule 238–39, 244
Hur, N. 120
HUS (high utilization sputtering) 49
HV-Sputter-24 48
Hybrid storage 218
Hypothetical models 87
Hypothetical models of centrosymmetric 87
Hypothetical models of centrosymmetric and noncentrosymmetric crystals 73

i

Iagrate, G.J. 55
IAS (ion-assisted sputtering) 49
IBM 241–42
IBM laboratories 64
IBM Zurich Laboratories 18
IBS (ion beam sputtering) 49
Idealized energy band diagram 156
Idealized hysteresis loops 101
IHC 180, 190–202
Important binary semiconductor materials 84
Important concepts 1, 18, 36, 148, 161, 175, 211
Important concepts of semiconductor materials 153, 158
InAlAs 241
InAs 46
India 143, 222, 253
Indigo 180
Indium 158
Indium antimonide 154, 167
Indium tin oxide *see* ITO (Indium tin oxide)
Infinite electrical conductivity 19
Infrared detection 146
InGaAs semiconductor 241
Ingram School xiv, 40
In_2O_3 173, 179–80
InP 3, 84
Insanity 57
InSb III 168
InSb 3, 46, 154, 167
  inspired 10
  insulating SiO_2 139
Integrated films 112, 114
Integration of multi-functional oxide 71
Intensity of sound 114
Interdiffused titanium layer 252
  intergranular capacitor 186
  intergranular resistance 186
International Table for Crystallographers 88
Intrinsic region 165
Introduction 1, 33, 57, 73, 95, 121, 153, 173, 215, 228–29, 247
Ions, central Ti^{4+} 140
Ireland 12
IrO_2 139
  iron-titanate 190
IR-UV 6
Ising model 235
Italy 24
ITO (Indium tin oxide) 173, 181, 183
ITO contacts 183

j

James Prescott Joule 208
James Roy Newman 121
Jan 51, 54
Japan 181
Jian Zhong xiv
Jie-Fang Li, D. 151
Jin, S. 245
  John 1, 18–19, 29, 33, 84–85, 93, 95, 147, 150, 153, 173, 181, 190, 247, 257, 259, 261, 263
Attia, John 213
  Kerr, John 250
Jona, F. 151
  Valasek, Joseph 123
Josephson, Brain David 22–23
Josephson effect 19, 22, 29
Josephson junction 19, 22–24, 30
Josephson junction device 242
Josephson junction effect 19
Josephson junction in high-speed data transfer 22
Josephson junctions in series 22
Josephson tunneling effect 18
Josiah, Willard Gibbs 34, 149
Joule, James 106
Joule heating 20, 208–9
Julléré, M. 245
Julliére's formula 241

k

Kahing, D. 213
Kao, K.C. 111, 120, 140, 150, 221, 228
Kasap, S. O. 31, 245, 255
Katiyar, R.S. 120
KCl 82
KDP 131, 252
KDP infrared detector 140
Keithley 145–46
Kelvin K 235, 263
Kerr, John 250
Kerr coefficient 250
Kerr effect 247, 249–50, 254
Kerr microscope 250

KH_2PO_4 131
Kinetic energy of emitted electron 8
Kirchhoff 192
Kishan, Alysha xiv
Kittel, C. 84–85, 93, 140, 151
KLN electro-optics 140
KN 129, 131
$KNaC_4H_4O_6$ 123, 131
$KNbO_3$ 36, 49, 53, 131, 140, 251
KN electro-optics 140
Knipping, Paul 61
Knudsen effusion cells and electron beam evaporators 47
Kotru, S. 120, 151
Kr 16–17, 75
KrF excimer laser 44
Kronig, Ralph 27–28, 30, 155
K-space 81
$KTaO_3$ 49, 53, 140
KT Electro-optics 140
KTN 49, 52–53, 129
KTN crystals 53
KTN electro-optics 140
KTN substrate 49
Kumar, A. 120

l

$La_{1-x}Sr_x$ 242
La_2O_3 186, 209
La^{3+} 207
$LaAlO_3$ substrate 241
$LaAlO_3$ 104
$LaCa_{0.77}Mn_{0.33}O_x$ 241
LAD (laser ablation deposition) 45, 55
LAM (laser ablation method) 43, 241
$LaMnO_3$ 104, 225, 242
Landau 121, 130
Lapis Electicus 143
Laplacian operator 12
Large solar panels 222
Laser-assisted film growth of electronic materials 44
La-Sr-Cu-oxides 129
Latin 123
Laue, Max von 61–62
Laue diffraction 61, 71
Laue diffraction pattern 62, 71
Laue method 63
Laue patterns 62
Laue's guidance 61
Laue's hunch 61
Laue X-ray diffraction method 61
Layers 42, 44, 45, 47, 49, 86, 106, 139, 186, 199, 210, 215, 240, 241
LCR meters 137
Lead-acid 218
LEDs (light-emitting diodes) 160, 179, 181
LEDs, blue 181
Leggett, Anthony J. 18
Lenz, Heinrich 208
Lenz law 168, 208, 239
Leonid 15
Levinson, L.L. 187, 213
Lewis, Gilbert N. 8
LFST (low-frequency sinusoidal temperature) 145
LFST technique 145–46
LGD 130, 140
LGD theory 132, 134, 140
Li 16, 245
Li-conducting Li-alumintirano-phosphate 209
LiF Zone 54
Light-emitting diodes *see* LEDs (light-emitting diodes)
Light waves propagate in space 252
Li Mg Mn 216
Limited Solubility in Solid Phase 37
Lin 214
Li-Na-ion BSH 220
$LiNbO_3$ (Lithium niobate) 52, 116, 140, 221–22, 247, 251
$LiNbO_3$-based waveguide 251
$LiNbO_3$ crystal 255
$LiNbO_3$ crystal substrate 252
$LiNbO_3$ substrate 252
$LiNbO_3$ surface 251
$LiNbO_3$ Trigonal 250
Linnaeus, Carl 143
LiO 42
Liquid Phase Epitaxy (LPE) 34, 43, 49, 54
Li Sodium 16
List of Nobel Prize in Physics 18
$LiTaO_3$ 52, 116, 140, 147, 221
Lithium niobate ($LiNbO_3$) 251, 254
Lithium tantalate 52, 111, 140, 147, 221
LMO 104
LN electro-optics 140
ln PO_2 210
ln VlnI 202
Local poling of ferroelectric polymers by scanning force microscopy 71
Lock-in-amplifier 112
Lode-stone 203
London penetration depth 20–21
Long term reliability 181
Lord Rayleigh 115
Los Alamos National 191
Los Alamos National Labs 237
Louis de Broglie 11, 29
Lowest symmetry 90
Low temperature multiferroics 103
Low-voltage STEMs 65
LPE *see* Liquid Phase Epitaxy (LPE)
LPE growth technique 49
LPE method 43, 49, 54
LPE method for film growth 49
LPE technique 54
LSM 225
LSMO 104, 242
LSMO electrodes 242
LT electro-optics and pyroelectric devices 140
LTP 42
LT $PbTiO_3$ 131
LTS (low temperature sintering) 41–42
Lu 245
$LuMnO_3$ 103
Lyman series 10
Lynn, E.G. 145, 151
Lyshevski, S.E. 55

m

Mach 252
Madame Curie of France 60
Madame Marie Curie 234
MAGFET 199, 212–13
Magnesium 16
Magnetic and electric parameters 232
Magnetic Curie point 191
magnetic Fe-atom 237
Magnetic field diagram 95, 99–100
Magnetic field effect transistor H-FET 191
Magnetic force microscope *see* MFM (Magnetic Force Microscope)
Magnetic GGG 49
Magnetic nature 16
Magnetic nature of electron 229, 235
Magnetic nature of superconductivity 20
Magnetic sensors, based VDR 204–5
Magnetization 234

Magnetoelectric effect in composites of piezoelectric and piezomagnetic phases 120
magneto-optic 250
magneto-optic Faraday 236
Magnetoresistance 205
Magneto-resistance *see* MR (magneto-resistance)
Magneto-resistive coefficient *see* MRC (magneto-resistive coefficient)
Magnetotransistor 203
Magnetron 48, 54
Magnifying power and resolution 59
Manufacturing cost 181
Marcos, San xiii–xiv, 40, 48, 66, 71
Martins, R. 213
Mass of neutron 259
Mass of proton 259
Mater 71, 120, 213
Mathematical representation 109
Mathematical representation of piezoelectric effects 109
Matrices 93, 120
Matthessen's rule 5
Mauguin method 88
Max R 203
Maximum MR peaks 205
maximum power 224
Max Planck Institute 19
Maxwell, James Clark 8, 24, 155
Maxwell relation 98
MBE (Molecular Beam Epitaxy) 34, 43, 46–47, 54, 104
MBE, poor man 47
MBE film growth technology 47
MBE laboratory 48
MBE method 46, 62
MBE systems 47
MBE technique 46–47, 54
MBE technology 47
MBE unit in operation for oxide growth 48
McCormac, M. 245
Mecklenborg, Mark xiv
Meissner, Walther 20–22
Meissner effect 20
Memory, tunable capacitors Fe-RAM non-volatile 122
MEMS 112, 118, 123, 222
MEMS actuator 116, 119, 222
MEMS applications 113
MEMS cantilever 117
MEMS devices 118
MEMS power generator 222
MEMS sensors 241
MEMS structures 118
MEMS technology 118
Mendeleev, Dmitri 15
MENU 1, 33, 57, 73, 95, 121, 153, 173, 215, 229, 247
MeRAM 105, 241
MERAM memory 105
MERAM technology 106
Mermin, N.D. 31
Merz, W.J. 125, 128, 137–38, 150–51
Metallic Bonding 74
Metallic Pb 50
Metallized path 115
Metal semiconductor contact 175
Meter 263
Methods for materials characterization 57, 59, 61, 63, 65, 67, 69, 71
Methods for powder compaction and densification 41
Methods for surface and structural characterization 57
Methods of ceramic processing 33, 38, 230
Methods of crystal growth 49, 53
MFM (Magnetic Force Microscope) 57, 68–70
MFM-generated image 70
MFM image 69
MFM magnetic force 71
MFM microscope 69
Mg 41, 81, 86
$MgAl_2O_4$ 41
Mg calcium 16
$MgCr_2O_4$ 207
MgO 82
$Mg_{0.5}W_{0.33}$ 103
Mhaisalker, S.G. 213
MHz 49, 55, 194, 198, 232, 239
Mica 4
Micromachined part 222
Microwave Engineering 150, 255
Miletus 203
Miller, William H. 80
Miller indices 73, 80–81, 92
Miller indices for planes and directions 79
Miller rule for indexing crystal directions 80
Miller's rules of indexing 80, 81
Miscible Systems 35
Mixed perovskite 103
Mixture $A_{0.5}B_{0.5}$ 36
MKS system 231
Mn Iron 17
Mn Mo 216
Mn_2O_3 191
Mn-doped PsB 193
Mn-doped pseudobrookite 191
MnFe 230
Mn-ferrite 234
MnO 102, 179, 234, 237
MnO_2 186
MnO_3 242
Mn-PsB 190–91, 193–94
MnPsB device 193
MnPsB voltage 194
MnTe 102
Modified electric field 96
Modified Hermann's nomenclature scheme 88
modified 119
modulated 24
MOG (metal oxide grains) 186
Mohan, G.R. 213
Molecular beam epitaxy *see* MBE (molecular beam epitaxy)
Molybdate $PbMoO_4$ 254
Momentum 13
Monoclinic biaxial 250
Morener, William E. 59
MOSFET (metal-oxide-semiconductor field effect transistor) 183, 196, 211
MOSFET structure 139, 196
MOSFET transistors 196, 242
Mostovoy, M. 120
Moulson, J. 147, 151, 214
MR (magneto-resistance) 205–6, 240–42, 244
MRAM (magnetic random access memory) 105
MR-based sensor 205
MRC (magneto-resistive coefficient) 201–2
MRC parameter 201
MRI (magnetic resonance imaging) 19
MR sensor 205
MR value 241
MTI Company 40
MTJ (multiferroic tunnel junctions) 105–6, 241
MTJ device 106
Müller, Alex K 18
Multi-ferroic magnetoelectrics 120
Multiferroics Phenomena 95, 99, 101

Multiferroic tunnel junctions *see* MTJ (multiferroic tunnel junctions)
Multifunctional magnetoelectric materials for device applications 120
Multifunctional nature of ferroelectrics 122
Multi-functional oxide 71
Mulyukov, R.R. 55
Munich 65
Munsee, C.L. 213
MW 123, 224–25
MW-IR Frequency 6

n

Na^+ –ions 82
NaCl 7, 38, 71, 74, 82, 86–87, 224
NaCl crystallizes in fcc structure 82
NaCl crystals alkali metals and halides 74
NaCl figure 84
NaCl molecule 74
Nagendra Nath 253
NaI 54
Na-ions 82
$NaKC_4H_4O_6$ 140
Nan, C.W. 120
NAND (Not-And) 105
Nanoscale technology 151
Nanoscience 42, 55
NASA 224
National high magnetic field laboratory 237
National Institute 15
Natural light 247
Nature of Electrical Conduction in 153–55
Nazarov, A. A. 55
Nazi Regime 14
Nb 19, 139, 146, 216
Nb^{5+} 207
Nb-doped PZT 145, 147
Nb doping 151
Nb doping level 146
Nb_2O_5 186
$Nb_{10}O_{30}$ BNN Electro-optics 140
$Nb_{10}O_{30}$ BSN Electro-optics Barium 140
NCS 131
Nd-doped yttrium aluminum garnet 252
Néel, Louis 237
Néel point 102–3, 230, 242–43
Néel temperature 141, 230, 238, 243
Néel theory 238
Néel theory of antiferromagnetism 238
Negative temperature coefficient *see* NTC (negative temperature coefficient)
Neon 16
Netherlands 18, 103, 163
New Delhi 171
New Mexico 237
Newnham, R.E. 93, 107, 120
Newton, Sir Isaac 12, 73
Newton's laws 12, 208
Newtonian acceleration 160
Newton's mechanics 12
New York 93, 120
New Zealand 10
n-GaAs 181
NH_2CH_2COOH 131, 140
NiCd 218
NiCd batteries 218
Nichrome 5
Niels Henrik David Bohr 10
Niels 236
$NiFe_2O_3$ 230
$NiFe_2O_4$ Nickel 242
$NiFe_2O_4$ 53, 235
Ni-ferrite 234–35
Night vision devices *see* NVD (night vision devices)
NiO 179, 207, 230, 234, 237
Niobate $Ba_{5x}Na_5$ 140
NIST 15, 22
NLC 185–86, 190, 192, 200, 202, 204–6, 212
NO_2 209
Nobel Committee 8
Nobel laureates 18
Nobel Lecture 95
Nobel Prize 18–19, 64
Nobel Prize, second 19
Nobel Prize in chemistry 10, 59
Nobel Prize in physics 7–8, 10, 12–14, 18, 22, 24, 29, 60,63, 181, 188, 190, 237, 240, 253
Noise 62
non-MEMS 220
Nonohmic contact 163, 178
Nonoxides 103
Non-polar 109
Normal electron 23, 29
Normalized MR 206
Norwegian-American physicist 22
Not-And (NAND) 105
Novel Magnetic Technologies 229, 239
NSEC response time detector 151
NSMs 42
NTC (negative temperature coefficient) 207, 209, 211
NTC sensor 174
NTC thermistors 209
NVD (night vision devices) 9, 252–53
Nye, J. E. 93, 120

o

O_3 141
observed MR 241
Ocean power 216
Ochsenfeld, Robert 20
Ochsenfeld effect 20–22
Oe 204–6, 211, 232, 236
Oersted 211, 232
Ohm's law 2, 22, 183, 189, 208
O-ions 75
open-circuit voltage 224
operating 47
Onnes, Heike Kamerlingh 18
Optical classification 250
Optical classification of crystals 250
Optical fibers and rectangular dielectric slab waveguides 251
Optical Waveguides 251–52
optical 252
Ordered configurations of ferromagnetic 238
Ordinary ball milling 39
Ordinary ray 249
Organic solids 75
Oriented Nb-doped Pb 151
oriented 236
Origin of Holes 153, 156
Origin of potential barrier 174
Origin of Voids and Atomic Packing Factor 73, 84
original 136, 218
Orlando, T. P. 18, 31
Ortega, N. 103, 105, 120
Orthorhombic Tetragonal 129
Output current 191, 198
Output transduction 221
Oxford Science Publications 171, 214
Oxford University Press 31, 91, 93, 120, 171, 214, 245, 261, 263
Oxford University Press Source 255
Oxide Co_3O_4 231
Oxide CuO 231

Oxide FeO 231
Oxide GeO 231
Oxide NiO 231
Oxide semiconductor materials 179
Oxides of perovskite structure 242
Oxide spintronics 245
Oxide TFT 183
  oxide-based 180
  oxide-based TFT 180
Oxygen, tetragonal TB 130
Oxygen B-atoms 235
Ozone 47

p

Padmini, P. 171, 213
Palladium (Pd) 9, 35
Pandey, Christa xiv
Pandey, R.K. 1–257, 259, 261, 263
Paraelectic phase 134
  parallel impedance 187
Parallelogram 89
Paramagnetic 16, 230–31, 238
Paramagnetic copper 231
Paramagnetism Paramagnetic materials 243
Parameters B_{rem} 232
parent IIHC 45varistor 198
Paris 148
Park 120, 213
Parkinson's disease 115
Pascal 35
Paschen series 10
Patent 151
Pauli, Wolfgang 14
Pauli's Exclusion Principle 1, 14–15, 19, 24, 27, 29–30, 238, 244
Pauli's selection rules 235
Pauw, van der, L.J. 163
Pauw method 163
Pb 17, 38, 86, 103, 131, 141, 216
Pb-based materials 103
Pb-based solid solution 141
PbF_2 50
Pb-ions 103
$Pb_2KNb_5O_{15}$ 130
$Pb_3Mg_3Nb_2O_9$ 127
$PbNb_2O_6$ 130
PbO 50, 204
PbO_2 50
PbO and boron oxide 50
Pb Pt St 216
PbS 82
PbSe 54, 167
$PbTa_2O_6$ 130
PbTe 54, 154, 166
$PbTiO_3$ 36, 51, 140–41, 221
$PbZrO_3$ 102, 140–42, 221
$PbZrO_3$ crystal 140
$PbZrO_3$ Perovskite 141
Pb-Zr-titanate 139
$PbZr_{1-x}Ti_xO_3$ 104, 140–41
peak MR 205–6
PE effect 222
PEMFC (proton exchange membrane fuel cell) 224–25, 227
PEMFC devices 224–25
PEMFC technology 224
PEM fuel cell 224
Penn State University 42
Penney, William 27, 30
Penney model 27–28, 155
Permanent Dipole Bonding 75
Perovskite $Bi_{1-x}Nd_xFeO_3$ 227
Perovskite calcium titanate ($CaTiO_3$) 55, 82
Perovskite $CuTiO_3$ 55
Perovskite Orthorhombic 18
Perovskite $TbMnO_3$ 103
Perovskite Tetragonal 18
Perovskite Variable 141
Pertinent properties of IHC 198
PFM (piezoelectric force microscope) 57, 68–71, 108, 126, 137–38
PFM micrograph 70
PFM microscope 71
PFM probes 69
PFN 103
PFN-Pb 103
PFT 103
PFW 103
PFW-Pb 103
Phase diagram of bismuth sodium titanate and barium titanate 141
Phase shifters 252
Philips Labs 163
Phillip, H.R. 187, 213
  phosphate 140
Phosphorous 158
Photon energy, single UV 46
Physical properties of crystals 93, 120
Physicists, celebrated English 115
Physics, recipients of Nobel Prize in 29, 60
Physics Nobel Prize 60–61
Pierce, John R. 190
  Pierre 60, 108, 234, 236
Pierre-Ernest Weiss 234
Piezo effects 118
Piezoelectric and allied phenomena 150
Piezoelectric charge and stress coefficients 113
Piezoelectric force microscope *see* PFM (piezoelectric force microscope)
Piezoelectric frequency oscillator 116
Piezoelectric PZN 51
Pi for ionic polarization 6
Pittman, G.E. 160, 171, 181, 213
PKN 130
Planck, Max 7–8, 10–11, 30
Planck constant/ Planck's constant 7–9, 11, 22, 26, 46, 159, 164, 212, 259
Planck constant, reduced 236
Planck's law of radiation 11, 46, 59, 159
Planck's photon energy 30
Planck's radiation law 7, 10
Planck's theory 11
Planes/unit cell Crystal structure Crystal unit cell 18
PLD (pulsed laser deposition) 43–46, 55, 104
PLD, daily maintenance 47
PLD chamber 45
PLD experiment 46
PLD growth 44
PLD growth chamber 45
PLD method 44–45, 104
PLD system 45
PLD technique 45
PLD unit 46
Plot for time-dependent voltage output for Haynes 168
PLZT 41, 108, 127, 253
PMN 108, 126–27, 149
PMN-PT 108, 127
PNZT 131, 145
PNZT film 145–46
Pockels cells 249
Pockels effect 247, 249–52, 254
Pockels effect and Kerr effect 247
Poisson equation 189
Poland 51, 54
Polarity/mobility 191
Polarization vectors in neighboring lattices 141
Polar-molecule-induced dipole bonds 75
  poled 146

Poling of samples for experiments 134
polished 166
Pollution control Radiometry Pyroelectric 122
Pollution monitoring 147
polycrystalline 111, 186
Poly-Si 139
Polyvinyl chloride 4, 111
Positive Sapphire Al_2O_3 Trigonal 250
Positive temperature coefficient *see* PTC (positive temperature coefficient)
Potassium 16
Potassium chloride 82
Potassium lithium niobate $K_5Li_2Nb_{10}O_{15}$ 140
Potassium niobate KNbO3 251
Potassium-sodium tartrate-tetrahydrate 131
Potassium tantalate niobate $KTa_{1-x}NbxO_3$ 140
Potential barrier WB 176
Potential barrier WC 178
Potential WC 178
Powder diffraction method 60
powder of 55
Prairie View A&M University xiv
Predictive Nature 86
Predictive Nature of Crystal Structure 73, 86
Prefixes commonly used 261
Prentice Hall 171
Presley, R.F. 183, 213
Primitive Cubic Structure 85
primitive 85
Principal bonds 74
Principal effect 96–97
Principles and Applications of Ferroelectricity 151
Principles and Applications of Ferroelectrics 93
Processing of electroceramics 33–35, 37, 39, 41, 43, 45, 47, 49, 51, 53, 55
producing high-quality 35
Producing NSMs 47
Production of birefringence 249
Droopad, Ravi xiv
Projector lens 64
prominent 36
Properties and applications of varistor 71
Properties and potential applications 202
PsB 180, 190–91, 203–5
PsB varistor 203
PsB VDR 203, 205
Pt/Al 176
PTC (Positive temperature coefficient) 4, 207, 209, 211
PTC and NTC thermistors 209
PTC devices 207
PTC effect in ferroelectric 207
PTC sensors 174
PTC thermistor 207
Pt/Si 178–79
Pt/Si contact 178–79
P-type conduction 153, 156
p-type Ge 171
P-type nature 164
P-type Si-substrate 139
P-type ZnO 181, 183
p-type 169–70, 178, 195, 196
Pulsed laser deposition *see* PLD (pulsed laser deposition)
Pump electron-gun 47
Pure DC 135
pure 185
PV 217
PVA 39
PVD (physical vapor deposition) 47
PV devices 223
PVDF copolymer 108
PV effect 222–23
Pyrex glass vessels 53
Pyroelectric coefficient Pi 98
Pyroelectric coefficients of selected materials 147
Pyroelectric TGS 53
Pyromagnetic effect 77
Pyrometer 45
Pyro-optic Effect 121, 147, 149
PZT 89, 104, 111–14, 117–18, 125, 129, 131, 138–42, 150, 221, 223, 227
PZT actuators 117
PZT cantilever 112–13, 117
PZT capacitors 141
PZT ceramic 147
PZT energy harvester 227
PZT ferroelectric film 104
PZT film cantilever 113
PZT films 105, 112
PZT materials 141
PZT MEMS cantilever 117
PZT Piezoelectric devices and memory 140

q

Qualitative comparison 231
Quantization of magnetic flux 22
Quantum Hall effect 169
Quantum Mechanics and Magnetism 238
Quartz SiO_2 Trigonal 250

r

Radiant Technologies 136
Radiation Law 7
Radio frequency *see* RF (radio frequency)
Radio frequency ID cards 122
Radio frequency magnetron sputtering method 43
Radiometry 147
Radon 16
Ragone, D.V. 228
Ragone chart 218
Ragone Plot 218
Rahman, Shafiqur 71
RAM *see* random access memory (RAM)
Ramamoorthy, Ramesh 103, 120
Raman, C.V. 253
Ramanujan, Srinivas 121
Random access memory (RAM) 105, 149, 241
Rapid cooling 50
Ratcliff, N.M. 214
Ravi Droopad 48, 66
Raw materials II 44
Raw materials III 44
RBS (Rutherford Back Scattering) 57, 67
RC circuit 135
Recent Applications of Ferroelectric Materials 121, 138
redox electrolytes 220
Reduced Planck constant 259
reduced 8
Refractive index of selected materials 248
Region, near-IR 182
Relationship MR 206
Relative emitted radiation 182
Reller, A. 228
remnant point 232

Representation by Tensors and Matrices 93, 120
Representation of coupled properties in solids 77
Residual gas measurement 47
Residual resistivity 5
Resistance temperature detectors *see* RTDs (resistance temperature detectors)
  resistive 106
Resistivity of CCTO 180
Resistivity of solids 4
Review of Battery Systems for Electrically Powered Vehicles 228
RF (radio frequency) 43, 114, 122–23, 150, 255
$RFeO_3$ 235
RF frequency 55
RFID 122
RFID tag 220
RF magnetron sputtering 49, 183
RF magnetron method 43
RF magnetron sputtering 49
RF magnetron sputtering method 47
RF sputtering 55, 104
RF transformers 239
RHEED 47, 55
RHEED device 45
RHEED Gun 45
RHEED screen 45
Richardson, Owen William 188, 213
Richardson constant 188, 212
Richardson equation 188
Richardson law 188
  Robert 18–19, 29
Rochelle salt 123, 131, 140, 150
Rodgers Library xiv
ROHM Co 138–39, 151
  role 215
Rohrer, Heinrich 64
ROM (read only memory) 105
Röntgen, Wilhelm C. 60
Röntgen-ray 60
Room temperature properties and potential applications 201
Room temperature pyroelectric coefficient and figure-of-merit 146
Room Temperature Uniaxial Pressing (RTUP) 38
Rotatable manipulator 48
Rotatable sample manipulator 45
Rotatable target assembly 48
Rotating target holder 46
Rotating/Tilting target 45
Roundy, C.B. 145, 151
Roundy method 145
Rowell, John 23
RSFQ (rapid single flux quantum) 22
RTA (rapid thermal annealing) 183
RTD device 207
RTD elements 206
RTDs (resistance temperature detectors) 206–7, 211
RTUP (room temperature uniaxial pressing) 38
RTUP method 41
Rubidium 16
Ruska, Ernest 63, 65
Russian chemist 15
Rutherford, Lord 10, 34, 57
Rutherford equation 66
Rutherford's model 10
Rydberg constant 10–11

S

SAE Technical Paper 228
Saturn-V Rocket 173
SAWs match 115
Sawyer 135–36, 150–51
Sb 157–58
SBN (Sr-Ba-niobate) 52, 130–31, 147, 150
SbSI 42, 148
SbSI Pyro-optic 140
Scanning tunneling microscope *see* STM (scanning tunneling microscope)
Scattered electrons Auger electrons 63
Scattering, small angle X-ray 60
Schad, R. 213
Scherrer Method 60
Schmid, H. 100, 120
Schönflies method 88
Schönflies School 88
Schottky, Walter H. 176, 196, 211
Schottky barrier 176, 179, 186, 188, 192, 212
Schottky barriers, double 188, 207
Schottky barrier height 175, 177–78, 211
Schottky diode 173–74, 176–78, 188, 196, 211–13
Schottky diode in electroceramics 176
Schottky diodes in back-to-back configuration 184
Schottky effect 188
Schottky gate 241
Schottky height 192
Schottky of Germany 176
Schottky thermionic emission (STE) 188
Schottky Transistor 195–96
Schrieffer, Robert 23
Schrödinger, Erwin 12, 24
Schrödinger equation 7, 11–13, 24, 28
Schrödinger's wave 28
Schrödinger's wave equation 12
Schrödinger's wave function 12
Schwing, U 204, 214
Scotland 250
Scotti, J.F 120
Sears 253
Secondary electron 65
Second electromagnetic coil 64
Second harmonic generator (SHG) 252
Second order phase transition 128–29
Second soaking cycle range 50
  second 29
Seebeck, Thomas Johann 164
Seebeck coefficient 165–66, 171, 191, 206
Seebeck coefficient for semiconductors 165
Seebeck coefficient of Ge 171
Seebeck Effect 164, 166, 171, 206
Seed holder 52
Selected antiferroelectric materials 141
Selected Crystal Systems 73, 81
Selected elector-optical crystals 251
Selected electro-optic applications 251
Selected ferroelectric materials 140
Selected metals and oxides 166
Selected piezoelectric materials 111
Selected single-phase multiferroic materials 103
Semiconductor BJT transistors 199
Semiconductor contacts 173–74
Semiconductor materials groups IV 154
Semiconductor MOS transistor 199
Semiconductor properties 3, 153, 162

Semiconductors 1–6, 16, 17, 24–27, 29, 42, 49, 53, 82–84, 121, 153–161, 164–166, 168, 169, 173–176, 179–181, 183, 206, 207, 209, 211
Semiprecious crystal tourmaline 98
Shamsuzzoha, M. 213
Sharma, P.A. 120
SHG (Second harmonic generator) 252
Shimizu, Y. 214
Shirane, G. 151
Shockley, William 190
Shockley experiment 167–68
Shockley method 166–67, 171
Short-circuit current density Jsc 224
Shuji Nakamura 181
Si_3N_4 69
Si_4 74
SiC-based Schottky 177
Siemen 212
Signature properties of ferroelectric materials 121, 123
Signature properties of superconductors 1, 19
Simmons, J. 228
Single crystal GaAs substrate 61
Single Crystal Growth Methods 49
single crystal of 203–4
Single crystal PsB 203
Single crystal quartz 116
Single Fe-atom 237
single 189
Sinhalese 143
Sinter 39
Sintering of nanosized ceramic powder 42
SiO 52
SiO_2 52–53, 74, 114, 116–17, 139, 154, 186, 211, 221–22, 248
SiO_2 cantilever 117
SiO_2 cantilever device 118
Si-technology 139
Sites, site A2 site B1 site B2 130
Sivanand, P.S. 214
Sn 17, 38, 84, 216
Snell's law 248
SnO_2 42, 173, 179–80, 183–84, 186, 209–11
SnO_2 alloy 173
SnO_2 varistors 185–86, 210
Sn-oxide 183
$Sn_{0.63}Pb_{0.37}$ 38
Socrates 203
SOFC (Solid Oxide Fuel Cells) 224–25, 227–28
SOFC cathodes 225
SOFC cells 224
SOFC devices 224–25
Soft ferrites 233
Solar 227
Solar CSP Geothermal 216
Solar energy and wind energy 215
Solar heating/cooling 216
Solar PV 216
Solid materials 1, 3, 5, 7, 9, 11, 13, 15, 17, 19, 21, 23, 25, 27, 29
Solid oxide fuel cells *see* SOFC (solid oxide fuel cells)
Solid solution 36–37
Solid solutions PFW-$PbTiO_3$ 103
Solid state 171
Solid state electron 213
Solid state physics 31, 93
Solid-sublimation-condensation process 47
Solution 9, 12, 13, 21–22, 24, 26, 27, 28, 35–37, 40, 42, 44, 49–53, 58, 59, 60, 62
Solving STE equations 189
Solymar, L. 31, 171, 214, 245, 251, 254–55, 261, 263
SONARs 108, 118
Song, X. 151
Song dynasty 229
Sons 1, 33, 84–85, 93, 95, 147, 150, 153, 173, 181, 247, 257, 259, 261, 263
SOPT 128
Sorbonne 148
Source Wavelength 59
Sources of vibration 221
South Asia 143
Spaldin, N.A. 99–100, 120
special 85
Spectrometer 166
Speed monitoring 115
Spin Hall effect 169
Spin-polarized injection 242
Spintronic material Co-La_{1-x}, promising 242
Split drain MOS structure 199
SPM (scanning probe microscopy) 57
Springer 79, 93, 120, 198
Springer License 204
Springer Verlag 151
Squattrito, P.J. 55
SQUID 19, 24, 30, 203
SQUID magnetometers 19, 22
Sr 139, 235
Sr Barium 16
$Sr_{1-x}Ba_xNb_2O_6$ 147
Sr_2 139
Sr_2CrRO_6 242
Sr-Ba-niobate *see* SBN (Sr-Ba-niobate)
Sr-Ce-Yb-oxide 209
$SrCO_3$ 40–41
$SrCO_3SrO$ 41
$SrCO_3TiO$ 41
$SrCO_3$ of SrO 41
$SrFe_{12}O_{19}$ 233
Sr-ferrite 233
Sr-ferrite Hard Small 239
Sri Lanka 143
Srinivasan, N. 159, 168, 171
Srivastava, C.M. 159, 168, 171
$SrNbO_3$ 130
SrO 40–41
$SrRuO_3$ 242
$SrTiO_3$ 4, 30, 36, 40–41, 66, 242, 248
$SrTiO_3$ melts 41
$SrTiO_3$ powder 41
$SrTiO_3$ unit cells 40
Sr_x TiO_3 242
Standard atmosphere 259
standard MOSFET 241
Standards 15
Stapleton, W.A. 71, 171, 213, 228
STE (Schottky thermionic emission) 188
Steel autoclaves work 53
STEM microscope 64–66
STE process 188
Sterling, C. xiv
Stern, Otto 14
STM (scanning tunneling microscope) 64, 68, 71, 108
STN 139, 141
STN memory cell 139
STO 62, 66, 242
Stockberger 34
Stockberger method growth 54
STO interface 66
STO layer 66, 242
Streetman, B.G. 171
strong Colombian 10
Strong thermal dependence of resistivity 4
strong 76
Structures associated 234
subject xiii

Substrate, n-Si 177
Supercapacitor CCTO 55, 225
Superconducting phase Cooper pairs 19
Superior Power 49
Superparamagnetism 230, 243
Sutanto, I. 71, 213
Switzerland 28, 64, 68
Symmetry elements for pyroelectric 90
Symmetry elements for piezoelectricity 109
Symmetry elements for piezoelectric materials 90
Symmetry elements of centrosymmetric group 90

t

Ta^{5+} BT 207
Takao 214
Tamil 143
Tamil Nadu 143
Ta_2Nb_2 139
Tate, J. 71, 213, 228
Taylor's series 250
TB (tungsten bronze) 127, 130–31, 150
TB family 130
TB ferroelectrics 130
$TbMnO_3$ 103
$TbMn_2O_3$ 103
TB structures 130
Tc 18–23, 35, 102, 124–26, 128–29, 131–34, 141–42, 148, 191, 207–8, 234, 237–38, 242
TCBCO 18
Tc temperature 20
Td 227
Teale, Gordon 51
Teller, Edward 215
Tellurium 166
Temperature coefficient of resistivity 5
Temperature dependence of critical magnetic field 21
Temperature dependence of ferroelectric parameters 125
Temperature dependence of inverse 133
Temperature dependence of magnetic parameters 234
Temperature dependence of resistivity of metals 5
Temperature gradient conditions BGO 54
TeO_2 90
TER 106
Tera 261
Tesla 19, 211, 231–32, 243, 263
Tetragonal Cubic 208
Tetragonal Orthorhombic 131
Tetragonal Uniaxial 250
Texas 40
Texas A&M University xiii–xiv, 21, 41, 191
Texas Instruments 51, 160, 181, 213
Texas State University xiii–xiv, 40, 48, 66, 71
TFT (thin-film transistor) 179–81, 183–84
TFT properties 181
TFT technology 183
TGS 131, 147
TGS infrared detector 140
Thallium 17
Theoretical considerations for varistors 173, 186
Theory of antiferroelectric crystals 151
Theory of superconductivity and superfluids 18
Thermal currents I1 177
Thermal properties of metals and semiconductors 24
Thermoelastic effect 96
Thin film ceramics 42
Thin-film forms 103
Thin-film transistor *see* TFT (thin-film transistor)
Thoramali 143
Ti^{4+} 127
Tiefel, T.H. 245
  time-dependent 13
  time-independent 13, 28
TiO_2 4, 30, 40–41, 55, 154, 173, 179–80, 183, 186, 209, 248
TiO_2 crystal 255
TiO_2 sensors 209
TiO_2 Tetragonal 250
TiO_2 waveguide 255
TiO_{2+} 40
TiO_3 147
$TiO_{3-x}BaTiO_3$ 141
Titania 17, 154
$Tl_2Ca_2Ba_2Cu_3O_{10}$ 18
TMR 241–42
TMR effect 241
TMR tunneling effect 242
Top seeded solution growth (TSSG) 52
Tower 135, 151
Tower circuit 135–36, 150
Toyosaki, H. 213
Traditional biomass Bio-heat Ethanol 216
Transconductor 191
Transducers and acoustic amplifiers 221
Transformers for low power applications 240
  transparent 183
  transparent SnO_2 183
Triple Point and Interfaces 34
Triple points of selected materials 35
Tryglycine sulfate 140
TSC (thermally stimulated currents) 145
TSSG (top seeded solution growth) 52
TSSG method 53
Tungsten 5
Tungsten bronze structures 121, 127, 130
Turmai 143
Tuscaloosa xiv, 46, 120
TV broadcasting 115
TV screen 64, 182
Two-dimensional atomic distribution 86
Typical examples of crystal structures 73, 82
Typical structures associated 229

u

U-238 15
Übung macht den Meister 33
UHF-MW 6
UHV (ultra-high vacuum) 46
UHV conditions 46
UHV environment 47
UHV-PLD-1X 45
Ultra 218
Ultra-sound waves 253
Ultra-violet *see* UV (ultra-violet)
Unbiased potential V0 200
Undetermined Signal 194
Unit Cell Triclinic 90
United States 15
University xiii–xiv, 18, 40, 46, 120
Unpolarized ray 249
US Defence Logistics Agency 218

US Department of Energy 237
US DoE 191
US military 220
US Patent 213
US Patent Number 171
US universities xiii
Uuo 15
UV (ultra-violet) 6, 9, 59–60, 179, 181–82, 212, 223, 227, 247
UV-blue 181
UV laser 46, 224
UV light 30, 64, 253
UV photon 46
UV radiation 46
UV range 180
UV source 59
UV wavelength 46

v

Vaccum 8
Vaccum level 174–75
Valasek, J. 138, 150
Valence band, n-Type semiconductor 175
Valent Fe-ions, mixed 243
  value of 185, 200
Values for Fermi energy 162
Values of Curie temperature of selected magnetic materials 234
Vapor phase method 42, 54
Varistor diodes 173, 184–85, 188–89, 212
Varistor-embedded devices 173, 190
Varistor microstructure 186
Varistor's NLC 205
  varistor's 186
VBT (voltage biased transistor) 190–91, 193–95, 197, 212
VBT, embedded 194
VBT device 193–96, 198
VBT transistor 193, 195, 197
VBT transistor device 196
VCCS 194, 212
VDR (voltage-dependent-resistor) 184, 203–6, 212–13
VDR characteristics, corresponding 203
VDR device 204–6, 212
VDR device changes 205
Veda, Sam 247
Velocity of light in material 248
Velocity of light in vacuum 248
Verneuil method 54
Viehland, A.S.B 151
Visible light microscopes 59
Voids and Atomic Packing Factor 73, 84
Voltage, differential Hall 199
Voltage biased transistor *see* VBT (voltage biased transistor)
Voltage biased varistor 190
voltage-dependent-resistor *see* VDR (voltage-dependent-resistor)
VPE technique growth of epitaxial films 55

w

Waals bond 74
Waals Bonding 75
Waals interaction 68
Walsh, D. 31, 171, 214, 245, 251, 254–55, 261, 263
  Walter, H. 176
Wang, C. 214
Weiss, Pierre 236–37, 244
Weiss law 20, 125–26, 132–34, 139, 142, 234, 244
Weiss-mean-field theory 234
Weiss model 235
Weiss theory 237
Westinghouse Electric Corporation 199
Whatmore, R.W. 146, 151
  white 61–62
Wiley 151, 214, 255
Wiley Eastern Limited 171
Wilhelm Conrad Röntgen 60, 103
Wilkins, Rick xiv
  Gibbs, Willard 131
  Penney, William 27
Wind Water Sun 216
WO_3 173, 209–11
WO_3 varistors 210
Work function W1 174
World War I 60

x

Xenon Xe 16
XPS (X-ray photoelectron spectroscopy) 34, 57, 66–67, 71
XPS method 66
XPS survey spectrum 67
XPS X-ray photoelectric spectroscopy 71
X-ray analysis 140
X-ray crystallography 60
X-ray diffraction
X-ray diffraction analysis 60
X-ray diffraction patterns for crystal structure 81
X-ray diffractometers 60, 65
X-ray gun 67
X-ray lithography position 108
X-ray of wavelength 71
X-ray photo-electron spectroscopy 67
  see also XPS (X-ray photoelectron spectroscopy)
X-ray reflectivity 60
X-rays 57–61, 63, 65–67, 71, 103
X-rays for chemical analysis 64
X-ray spectrometer 65
X-rays secondary 63
X-ray tool 61
XRD (X-ray diffraction) 14, 39, 57, 60–61, 71, 81
XRD, short wavelength X-rays 60
XRD diffractometer 60
XRD method of characterizing materials 60
XRD pattern 61–62, 71

y

$YaBa_2Cu_3O_7$ 18
YAG 52, 252
Y-Al-garnet 52
Yamada, Y. 213
Yang, Chen Ning 95
Yattria 209
Yattria stabilized zirconia (YSZ) 209, 225
YBaCu-oxide 83
YBCO 18, 21, 41, 83
YBCO in superconducting state 21
YBCO sample 21
$YbMnO_3$ 103
YIG 51
Yin, L. 214
$YMnO_3$ 103
Yousafzai, Malala xiii
Y-Sc-Ga garnet 52
YSGG 52
YSZ (Yattria stabilized zirconia) 209, 225

z

Zeeman Effect 11
Zehnder interferometer 252
Zepf, V. 216, 228
Zhang, L. 214
Zhong, Jian 112–13, 120, 151
Ziman model 27
Zinc (Zn) 17, 84, 86, 234

Zinc oxide (ZnO) 42, 53, 84, 113, 154–55, 173, 179–81, 184–86, 209–11, 242, 251
Zinc sulfide (ZnS) 17, 53, 83–84, 156, 254
Zirconate titanate $PbZrxTi_{1-x}O_3$ 140
Zn atom 84
Zn ferrite 232
$ZnCr_2O_4$ 207
$ZnCr_2Se_4$ 103
$ZnFe_2O_4$ 235
Zn-ferrites 233, 235
Zn-ferrite Soft 239
Zn-ferrites Soft Used 239
ZnO and SnO_2 varistors 210
ZnO-based homogeneous 183
ZnS crystal 255
ZnO grain 189
ZnO matrix 185–86
ZnO substrates 183
ZnO varistor in comparison 185
ZnO varistors 184–87, 189–90
ZnO varistors for high-voltage applications 185
ZnSe 17, 182
ZnTe 17
Zr 81, 131
ZrO_2 225
$Zr_{0.2}Ti_{0.8}$ 103
Zürich 64